NSN 5961-00-252-2432

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-252-2432 **Inclosure Material:** Metal **Overall Length:** 2.100 inches **Overall Height:** 0.635 inches **Overall Width:** 0.630 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 420.0 reverse voltage, total rms and 600.0 working peak reverse voltage, peak total value and 720.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 50.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Terminal Type And Quantity:** 1 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: No